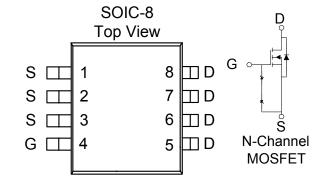
N-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
V _{DS} (V)	V) $r_{DS(on)} m(\Omega)$ $I_D (A)$				
60	$82 @ V_{GS} = 10V$	±4.6			
	$115 @ V_{GS} = 4.5V$	±3.9			

- Low $r_{DS(on)}$ provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Symbol	Symbol Limit U		
Drain-Source Voltage			V_{DS}	60	V	
Gate-Source Voltage			V_{GS}	±20	V	
	T _A =	=25°C	т	±4.6		
Continuous Drain Current ^a	T _A =	=25°C =70°C	1D	±4.0	A	
Pulsed Drain Current ^b			I_{DM}	±25		
Continuous Source Current (Diode Conduction) ^a				2	A	
D	T _A =	=25°C	D	3.1	W	
Power Dissipation ^a	T _A =	=25°C =70°C	PD	2		
Operating Junction and Storage Temperature Range			T_{J}, T_{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
	t <= 10 sec	D	40	°C/W			
Maximum Junction-to-Ambient ^a	Steady State	$R_{ heta JA}$	80	°C/W			

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Conditions	Limits			Unit		
Talallect	Symbol	Test Conditions	Min	Тур	Max	OIII		
Static								
Cate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1					
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current	IDSS	$V_{DS}=60 \text{V}, V_{GS}=0 \text{V}$			1	uA		
Zeto Gate voltage Dain Current	IDSS	$V_{DS} = 60 \text{ V}, V_{CS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$	2		25	uA		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α		
D : G . G . D A		$V_{GS} = 10 \text{ V, I}_{D} = 4.6 \text{ A}$	8		86			
Drain-Source On-Resistance ^A	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 3.9 \text{ A}$			115	mΩ		
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_{D} = 4.6 \text{ A}$		11		S		
Diode Forward Voltage	V _{SD}	$I_S = 20 A, V_{GS} = 0 V$		1.1		V		
Dynamic ^b								
Total Gate Charge	Qg	V _{DS} =30 V, V _{GS} =4.5 V, I _D =4.6 A		3.6		nC		
Gate-Source Charge	Q_{zs}			1.8				
Gate-Drain Charge	Qgd			1.3				
Turn-On Delay Time	td(on)			9				
Rise Time	tr	$V_{DD}=30 \text{ V}, R_L=30 \Omega$, $I_D=1 \text{ A},$ $V_{GEN}=10 \text{ V}$		10		nS		
Turn-Off Delay Time	td(off)			21				
Fall-Time	tf			8		[]		

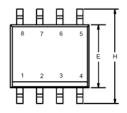
Notes

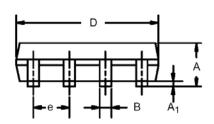
- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

